



BC846BLP4

65V NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

- Low Collector-Emitter Saturation Voltage, V_{CE(sat)}
- Ultra-Small Leadless Surface Mount Package
- Totally Lead-Free & Fully RoHS Compliant (Note 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: X2-DFN1006-3
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper leadframe. Solderable per MIL-STD-202, Method 208 (4)
- Weight: 0.0009 grams (Approximate)

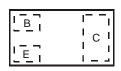
X2-DFN1006-3



Bottom View



Device Symbol



Top View Device Schematic

Ordering Information (Note 4)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
BC846BLP4-7B	3S	7	8	10,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com.

Marking Information

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Top View Bar Denotes Base and Emitter Side

3S = Product Type Marking Code



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	80	V
Collector-Emitter Voltage	V_{CEO}	65	V
Emitter-Base Voltage	V_{EBO}	6	V
Collector Current - Continuous	lc	100	mA
Peak Collector Current	I _{CM}	200	mA
Peak Emitter Current	I _{EM}	200	mA

Thermal Characteristics

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 5)	В	0.46	W	
Power Dissipation	(Note 6)	$ P_D$	1		
Thermal Resistance, Junction to Ambient	(Note 5)	D	272	°C/W	
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{ hetaJA}$	120		
Thermal Resistance, Junction to Leads (Note 7)		$R_{ heta JL}$	110	°C/W	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C		

ESD Ratings (Note 8)

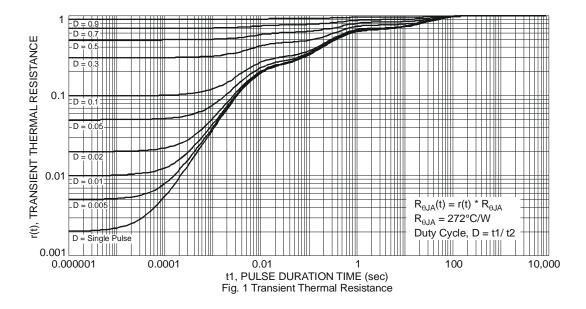
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

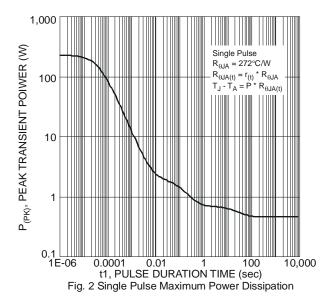
Notes:

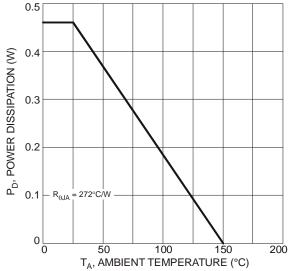
- 5. For a device surface mounted on minimum recommended pad layout FR-4 PCB with single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition. The entire exposed collector pad is attached to the heatsink.
- 6. Same as note 5, except device is surface mounted on 25mm X 25mm collector pad heatsink with 1oz copper.
- 7. Thermal resistance from junction to solder-point (at the end of the collector lead). 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics









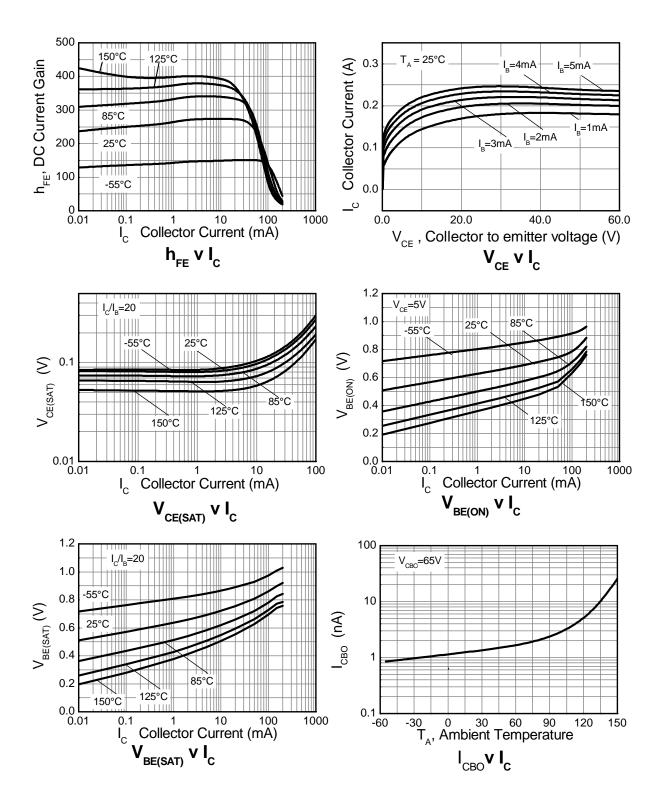
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV _{CBO}	80		_	V	$I_C = 100 \mu A, I_E = 0$
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	65	_		V	$I_C = 10 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	BV _{EBO}	6			V	$I_E = 100 \mu A, I_C = 0$
Collector Cutoff Current	I _{CES}	_	_	15	nA	V _{CE} = 65V
Collector Cutoff Current	I _{CBO}	_	_	15	nA	V _{CB} = 40V
	ICBO			5.0	μΑ	$V_{CB} = 30V, T_A = +150^{\circ}C$
ON CHARACTERISTICS (Note 9)						
DC Current Gain	h _{FE}	200	270	450	_	$V_{CE} = 5V, I_{C} = 2.0 \text{mA}$
Collector-Emitter Saturation Voltage	V _{CE(sat)}		90	250	mV	$I_C = 10 \text{mA}, I_B = 0.5 \text{mA}$
Concolor Entitles Calaration Voltage	V CE (sat)		220	600		$I_C = 100 \text{mA}, I_B = 5.0 \text{mA}$
Base-Emitter Saturation Voltage	Vest		720	900	mV	$I_C = 10mA, I_B = 0.5mA$
Dase Efficie Cataration Voltage	V _{BE(sat)}		870		111 V	$I_C = 100 \text{mA}, I_B = 5.0 \text{mA}$
Base-Emitter Voltage	V _{BE(on)}	580 —	650	700	mV	$V_{CE} = 5V, I_{C} = 2.0 \text{mA}$
			_	770		$V_{CE} = 5V$, $I_C = 10mA$
SMALL SIGNAL CHARACTERISTICS (Note 9)	SMALL SIGNAL CHARACTERISTICS (Note 9)					
Input Capacitance	C _{ibo}	_	6.7	_	pF	$V_{CB} = 5V$, $f = 1.0MHz$
Output Capacitance	C_obo	_	1.76	_	pF	$V_{CB} = 10V, f = 1.0MHz$
Current Gain-Bandwidth Product	f _T	100	300		MHz	$V_{CE} = 5V, I_{C} = 10mA, f = 100MHz$
Noise Figure	NF	_	2	10	dB	$V_{CE} = 5V$, $I_{C} = 200\mu A$, $R_{S} = 2.0k\Omega$, $f = 1.0kHz$, $\Delta f = 200Hz$
Delay time	t _d	_	11.2	_	ns	.,
Rise time	t _r	_	59.7		ns	$V_{CC} = 30V$,
Storage time	ts		190.8		ns	$I_C = 150 \text{mA},$ $I_{B1} = I_{B2} = 15 \text{mA}$
Fall time	t _f		108.6	_	ns	181 – 182 – 1911IV

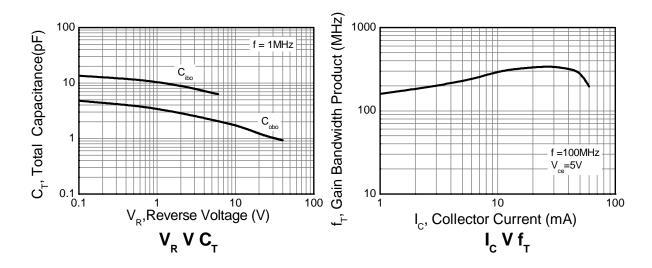
Note: 9. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.



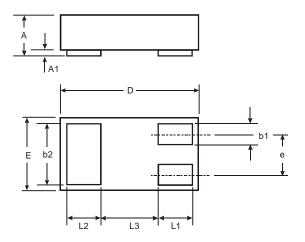
Typical Electrical Characteristics





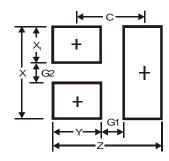


Package Outline Dimensions



X2-DFN1006-3					
Dim	Min	Max	Тур		
Α	_	0.40	_		
A1	0	0.05	0.03		
b1	0.10	0.20	0.15		
b2	0.45	0.55	0.50		
D	0.95	1.05	1.00		
Е	0.55	0.65	0.60		
е	_	_	0.35		
L1	0.20	0.30	0.25		
L2	0.20	0.30	0.25		
L3			0.40		
All Dimensions in mm					

Suggested Pad Layout



Dimensions	Value (in mm)		
Z	1.1		
G1	0.3		
G2	0.2		
Х	0.7		
X1	0.25		
Υ	0.4		
С	0.7		



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